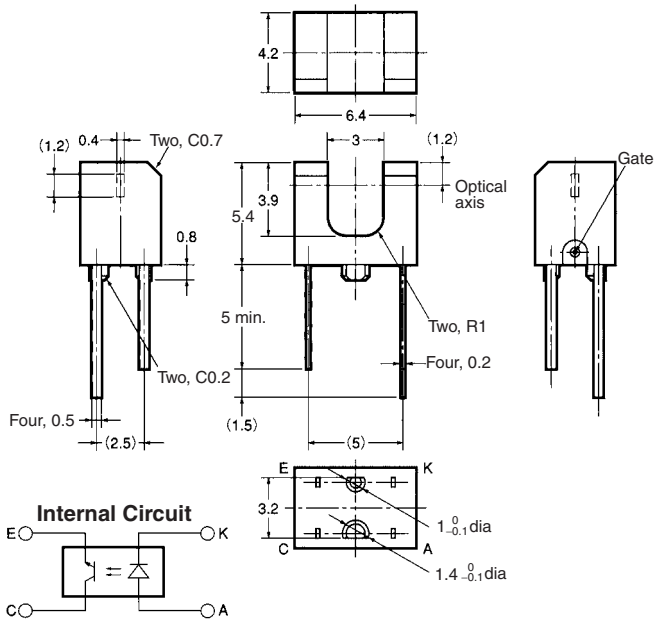
# Photomicrosensor (Transmissive)
# EE-SX1106

⚠ **Be sure to read *Precautions* on page 25.**

## ■ Dimensions

**Note:** All units are in millimeters unless otherwise indicated.




| Terminal No. | Name |
|---|---|
| A | Anode |
| K | Cathode |
| C | Collector |
| E | Emitter |

Unless otherwise specified, the tolerances are ±0.2 mm.

## ■ Features

- Ultra-compact with a slot width of 3 mm.
- PCB mounting type.
- High resolution with a 0.4-mm-wide aperture.

## ■ Absolute Maximum Ratings (Ta = 25°C)

| Item | | Symbol | Rated value |
|---|---|---|---|
| **Emitter** | **Forward current** | $I_F$ | 50 mA (see note 1) |
| | **Pulse forward current** | $I_{FP}$ | --- |
| | **Reverse voltage** | $V_R$ | 5 V |
| **Detector** | **Collector–Emitter voltage** | $V_{CEO}$ | 30 V |
| | **Emitter–Collector voltage** | $V_{ECO}$ | 4.5 V |
| | **Collector current** | $I_C$ | 30 mA |
| | **Collector dissipation** | $P_C$ | 80 mW (see note 1) |
| **Ambient temperature** | **Operating** | Topr | –25°C to 85°C |
| | **Storage** | Tstg | –30°C to 85°C |
| **Soldering temperature** | | Tsol | 260°C (see note 2) |

**Note: 1.** Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

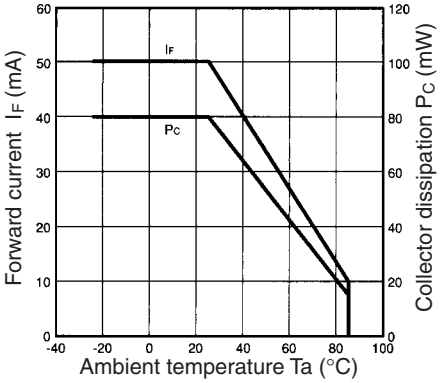
**2.** Complete soldering within 3 seconds.

## ■ Electrical and Optical Characteristics (Ta = 25°C)

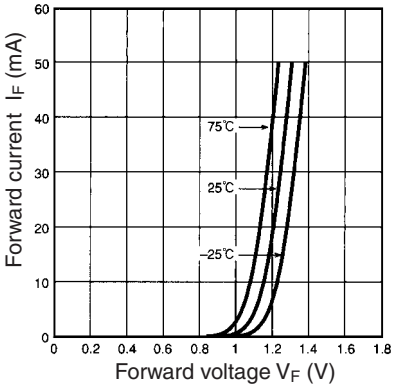
| Item | | Symbol | Value | Condition |
|---|---|---|---|---|
| **Emitter** | **Forward voltage** | $V_F$ | 1.3 V typ., 1.6 V max. | $I_F$ = 50 mA |
| | **Reverse current** | $I_R$ | 10 μA max. | $V_R$ = 5 V |
| | **Peak emission wavelength** | $\lambda_P$ | 950 nm typ. | $I_F$ = 50 mA |
| **Detector** | **Light current** | $I_L$ | 0.2 mA min. | $I_F$ = 20 mA, $V_{CE}$ = 5 V |
| | **Dark current** | $I_D$ | 500 nA max. | $V_{CE}$ = 10 V, 0 ℓx |
| | **Leakage current** | $I_{LEAK}$ | --- | --- |
| | **Collector–Emitter saturated voltage** | $V_{CE}$ (sat) | 0.4 V max. | $I_F$ = 20 mA, $I_L$ = 0.1 mA |
| | **Peak spectral sensitivity wavelength** | $\lambda_P$ | 800 nm typ. | $V_{CE}$ = 5 V |
| **Rising time** | | tr | 10 μs typ. | $V_{CC}$ = 5 V, $R_L$ = 100 Ω, $I_F$ = 20 mA |
| **Falling time** | | tf | 10 μs typ. | $V_{CC}$ = 5 V, $R_L$ = 100 Ω, $I_F$ = 20 mA |

## ■ Engineering Data

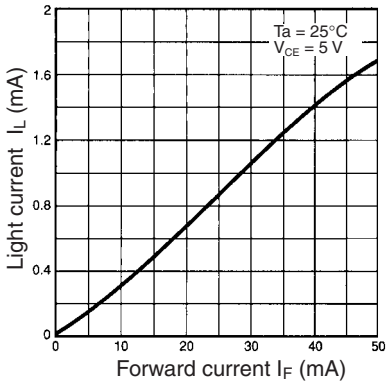
### Forward Current vs. Collector Dissipation Temperature Rating



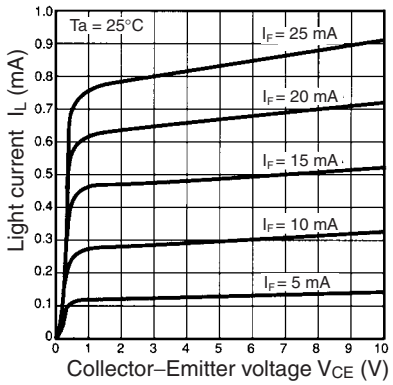

### Forward Current vs. Forward Voltage Characteristics (Typical)



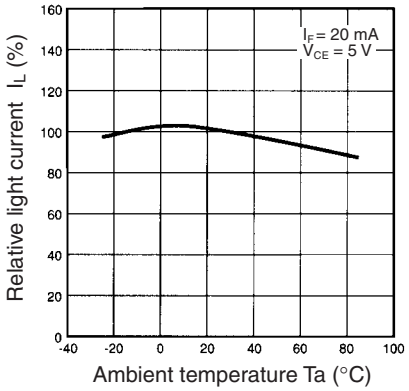

### Light Current vs. Forward Current Characteristics (Typical)



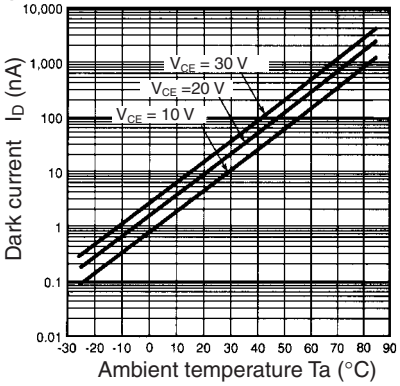

### Light Current vs. Collector−Emitter Voltage Characteristics (Typical)



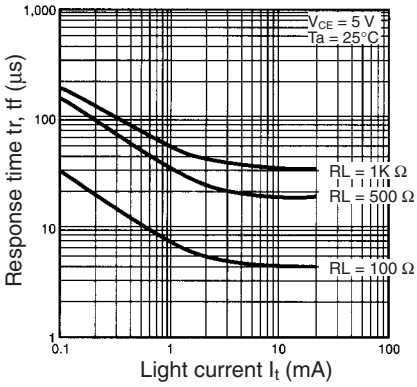

### Relative Light Current vs. Ambient Temperature Characteristics (Typical)



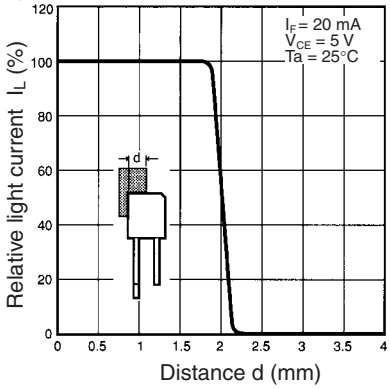

### Dark Current vs. Ambient Temperature Characteristics (Typical)




### Response Time vs. Light Current Characteristics (Typical)




### Sensing Position Characteristics (Typical)

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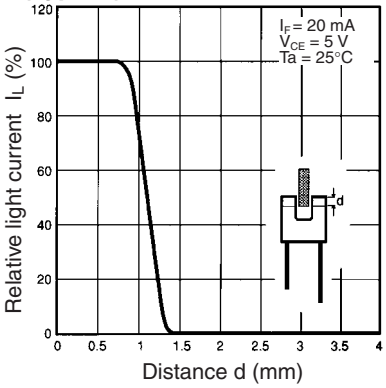


### Response Time Measurement Circuit

